TECHNICAL DATA
PART NUMBER: SEN-5632, REV A

Three-Phase MOSFET/IGBT Bridge Driver

Absolute Maximum Rating
Absolute Maximum Rating indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance is specified under board mounted and still air conditions. Die used is IR2135.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
High Side Floating Supply Voltage	$V_{B1,2,3}$	-0.3	-	625	V
High Side Floating Supply Voltage	$V_{S1,2,3}$	$V_{B1,2,3}$ - 25	-	$V_{B1,2,3}$ + 0.3	V
Supply Voltage	V_{CC}	-0.3	-	25	V
Logic Ground	V_{SS}	- 0.3	-	V_{CC} + 0.3	V
Logic Input Voltage ($\overline{HIN}$, $\overline{LIN}$, ITRIP $\overline{FLT\text{-}CLR}$, SD)	V_{IN}	V_{SS} - 0.3	-	V_{CC} + 0.3	V
Op-Amp Input Voltage	$V_{IN\text{-}Amp}$	V_{SS} - 0.3	-	V_{CC} + 0.3	V
$\overline{FAULT}$ Output Voltage	V_{FLT}	V_{SS} - 0.3	-	V_{CC} + 0.3	V
Thermal Resistance	R_{thjA}		-	50	^{O}C/W
Junction Temperature	T_j	-55	-	150	^{O}C
Lead Soldering Temperature, 10 sec	T_L	-	-	250	^{O}C

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
High Side Floating Supply Voltage	$V_{B1,2,3}$	$V_{S1,2,3}$ + 10	-	$V_{S1,2,3}$ + 20	V
High Side Floating Supply Voltage	$V_{S1,2,3}$	-5	-	300	V
Supply Voltage	V_{CC}	10	-	20	V
Logic Ground	V_{SS}	- 5	-	5	V
Logic Input Voltage ($\overline{HIN}$, $\overline{LIN}$, ITRIP $\overline{FLT\text{-}CLR}$, SD)	V_{IN}	V_{SS}	-	V_{SS} + 5	V
Op-Amp Input Voltage	$V_{IN\text{-}Amp}$	V_{SS}	-	V_{SS} + 5	V
$\overline{FAULT}$ Output Voltage	V_{FLT}	V_{SS}	-	V_{CC}	V

Dynamic Characteristics

V_{CC}=$V_{BS1,2,3}$ = 15V, $V_{S1,2,3}$ = V_{SS}, C_L = 1 nF

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Turn-On Propagation Delay	V_{IN} = 0 & 5V $V_{S1,2,3}$ = 0 to 300V	t_{on}	500	750	1000	nsec
Turn-Off Propagation Delay		t_{off}	450	700	950	nsec
Turn-On Rise Time		t_r	-	75	150	nsec
Turn-Off Fall Time		t_F	-	35	70	nsec
SD to Output Shutdown Propagation Delay	V_{IN}, V_{ITRIP} = 0V, V_{SD} = 0 & 5V	t_{sd}	500	750	1000	nsec
ITRIP to Output Shutdown Propagation Delay	V_{IN} = 0V, V_{ITRIP} = 0 & 5V	t_{itrip}	600	850	-	nsec
ITRIP Blanking Time	V_{ITRIP} = 1V	t_{bl}	-	400	-	nsec
ITRIP to FAULT Propagation Delay	V_{IN} = 0V, V_{ITRIP} = 0 & 5V	t_{flt}	400	650	900	nsec
FAULT-CLR to FAULT Clear time			600	850	1100	nsec
Input Filter Time ($\overline{HIN}$, $\overline{LIN}$, & SD)	V_{IN} = 0 & 5V	t_{fil}		310		nsec
Deadtime, LS Turn-Off to HS Turn-on & HS Turn-Off to LS Turn-On	V_{IN} = 0 & 5V	DT	-	250	-	nsec

Static Characteristics

V_{CC}=$V_{BS1,2,3}$ = 15V, $V_{S1,2,3}$ = V_{SS}

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Logic “0” Input Voltage (Output = LO)		V_{IH}	2.2	-	-	V
Logic “1” Input Voltage (Output = HI)		V_{IL}	-	-	0.8	V
Logic “0” Fault Clear Input Voltage		$V_{FCLR,IH}$	2.2	-	-	V
Logic “1” Fault Clear Input Voltage		$V_{FCLR,IL}$	-	-	0.8	V
SD Input Positive Going Threshold		$V_{SD,TH+}$	-	1.8	-	V
SD Input Negative Going Threshold		$V_{SD,TH-}$	-	1.5	-	V
ITRIP Input Positive Going Threshold		$V_{IT,TH+}$	-	0.485	-	V
ITRIP Input Negative Going Threshold		$V_{IT,TH-}$	-	0.400	-	V
Quiescent V_{CC} Supply Current	V_{IN} = 0V, or 5V	I_{QCC}	-	4	-	mA
Supply Under Voltage Positive Going Threshold		V_{CCIUV+} V_{BSIUV+}	-	10.4	-	V
Supply Under Voltage Negative Going Threshold		V_{CCIUV-} V_{BSIUV-}	-	9.4	-	V
Output High Short Circuit Pulsed Current	V_{OUT} = 0V, V_{IN} = 0V, tp < 10µsec	I_{O+}	200	250	-	mA
Output Low Short Circuit Pulsed Current	V_{OUT} = 0V, V_{IN} = 0V, tp < 10µsec	I_{O-}	420	500	-	mA

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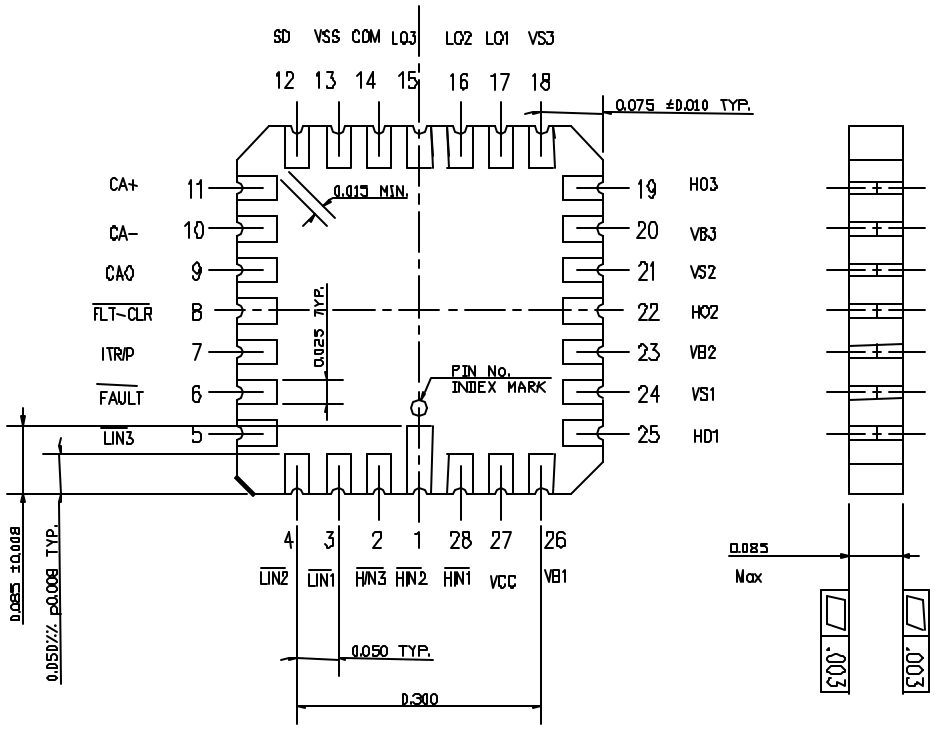
Package Layout:



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